

PDF DATA SHEET

EFORCEAUSTRALIA PTY.LTD ACN:159 503 401

MDL-III-808R/1~500mW

INFRARED DIODE LASER AT 808nm

Diode infrared laser module at 808nm is made features of ultra compact, long lifetime, low cost and easy operating, which is used in measurement, communication, spectrum analysis, etc.



SPECIFICATIONS

Wavelength (nm)	808 ± 3			
Output power (mW)	>1, 100, 200,, 300 >30		300,, 500	
Energy distribution	Even			
Beam Spot	Round			
Power stability (rms, over 4 hours)	<1%, <3%, <5%			
Warm-up time (minutes)	<5			
Beam divergence, full angle (mrad)	<8.0 <18		6. 0	
Dimensions of beam at the aperture (mm)	~2.0 ~2.0			
Beam height from base plate (mm)	24. 8			
Operating temperature (°C)	10~35			
Power supply (90-264VAC or 5VDC)	PSU-III-LED	PSU-III-FDA	PSU-III-OEM	
Modulation option	TTL/Analog 1Hz-5KHz, 1Hz-10KHz, 1Hz-30KHz, and TTL on/off			
Expected lifetime (hours)	10000			
Warranty	1 year			





